Superconducting SET with tunable electrom agnetic environm ent

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A bstract

We have studied the environmental e ect on superconducting single-electron transistors (S-SETs) by biasing S-SETs with arrays of small-capacitance dc SQUIDs, whose e ective impedance can be varied in situ. As the zerobias resistance of the arrays is increased, C oulom b blockade in the S-SET becomes sharper, and the gate-voltage dependence changes from e-periodic to 2e-periodic. The SQUID arrays could be used as on-chip noise liters.

Key words: Sm all-capacitance Josephson junction; Single-electron transistor; Electrom agnetic environment; Coulom b blockade

1. Introduction

Sm all-capacitance Josephson junction has been playing an important role in studying the interplay between quantum mechanically conjugate valuables, the Josephson phase and the charge on the island electrode [1]. It is also a promising candidate for solidstate realizations of quantum computing [2]. In this system, coupling to an electrom agnetic environment is a key issue. The coupling in uences the interplay between the phase and the charge. Moreover, it is a m a jor source of decoherence in quantum bits.

In this work we study the environmental electron superconducting single-electron transistors (S-SETs), which are building blocks of nano-circuits. The electron of dissipation on S-SETs have been investigated by capacitively coupling a two-dimensional electron gas to an S-SET β . We take a dimensional electron discribed in the next section.

2. Experim ent

We have biased S-SETs with one-dimensional (1D) arrays of sm all-capacitance dc superconducting quantum interference devices (SQUIDs) as shown in Fig. 1. W ith the SQUID con guration, the e ective impedance of the arrays can be varied in situ by applying a weak (1 10 mT) external magnetic ed B, i.e., the arrays are tunable environment [4(6] for the SET.For a scanning electron micrograph of a SQUID

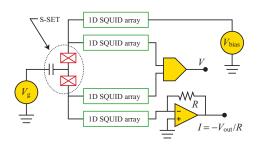


Fig.1. Schem atic diagram of the sam ple and the circuit.

array, see Fig. 1 of Ref. [6]. We measured the SET in a four-point conguration, where the bias was applied through one pair of SQUID leads and the potential dierence was probed through the other pair of leads. The SQUID arrays could be measured in a two-point conguration on the same side of the SET, and the zero-bias resistance R_0^0 obtained in this measurement may characterize the environment [4].

The sam ples consist of A $l/A l_2O_3/A l$ junctions fabricated on a SiO $_2/Si$ substrate. The area of each junction in the SET is 0:1 0:1 m², so that the charging energy of the SET is on the order of 1 K.

3. Results and discussion

W e show in Fig. 2 low-tem perature (T = 0.02 K) current-voltage (I-V) curves of an S-SET in di erent environm ents, $R_0^0 = 0.2$ M (B = 0) for a and $R_0^0 = 0.3$ G (B = 6.8 m T) for b. Here, the tem perature is 0.02 K and the gate voltage, V_g , is 0. For the sam –

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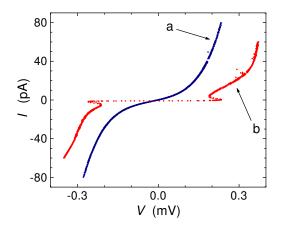


Fig. 2. Current-voltage characteristics of a superconducting SET at T = 0.02 K in di erent environm ents.

ple in Fig. 2, the norm al-state resistance of the SET is 0.10 M $\,$, so that the Josephson energy is estim ated to be 0.1 K . The parameters of the SET should be the sam e for the two curves in Fig.2, because the SET does not have a SQUID con guration and the eld applied here is much smaller than the critical eld for Al lm s (0:1 T). The environment for the SET (the SQUID arrays), however, is strongly varied with B. The behavior of the SET dem onstrated in Fig. 2 does not result from the magnetic-eld in uencing the I-V curve of the SET, but rather from an environmental e ect on the SET.W hile Coulomb blockade in curve a is rounded, that in curveb is sharp.Furtherm ore, curveb has a back-bending' in the low -current part, which is evidence of coherent single-Cooper-pair tunneling [5]. For the di erence between curves a and b quasiparticles generated by external noise may be responsible, because no lter has been installed in or at the top of our cryostat. A su ciently large R_0^0 would weaken the coupling to the noise source and suppresses the quasiparticle generation.

W e have also examined the dependence on V_q as shown in Fig. 3. We xed V_{bias} (see Fig. 1) and measured the current I as a function of V_q . W hen V, the the potential di erence across the SET is large com pared to the voltage drop at the other parts of the circuit, V is nearly independent of Vg. This is the case for the upper data set in Fig. 3 ($R_0^0 = 0.2 \text{ M}$, B = 0), and V = 0:1 mV. In the opposite case, V also oscillates as a function of $V_{\rm q}$, which makes the amplitude of the current oscillation sm all. In the case of the lower data set in Fig. 3 ($R_0^0 = 0.3 \text{ G}$, B = 6.8 mT), V oscillates between 0.1 and 0.3 m V. Nevertheless, it is still possible to clearly observe the oscillation of I. In Fig. 3, $V_{\rm g}\,$ is norm alized by e=C $_{\rm g}$, where the gate capacitance C_g = 6 aF is estimated from a similar gatesweep measurement in a strong enough magnetice eld (B = 0:1 T) to drive the sam ple into the norm alstate.

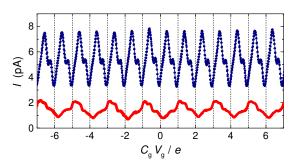


Fig.3. Current vs.norm alized gate voltage at T = 0.02 K for the same superconducting SET as in Fig.2. The upper (lower) data set was taken in the same environment as for curve a (b) in Fig.2.

By tuning the environment, the V_g dependence changes from e-periodic to 2e-periodic, i.e., the dominant tunneling process changes from quasiparticle tunneling to C coper-pair tunneling. This observation is consistent with the picture in the end of the preceding paragraph that the quasiparticle generation is suppressed by the SQUID arrays when the arrays have a su ciently large R_0^0.

4. Conclusion

W e could sharpen C oulom b blockade in the S-SET and change the dependence on the gate voltage from eperiodic to 2e-periodic, by tuning the electrom agnetic environment composed of small-capacitance SQUID arrays in the immediate vicinity of an S-SET. The SQUID arrays behaved as elective noise liters.

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